

# Transmission electron microscopy characterization of spark plasma sintered $\text{ZrB}_2$ ceramic

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## Abstract

Microstructures of  $\text{ZrB}_2$  ceramics consolidated by hot-pressing and spark plasma sintering were investigated by transmission electron microscopy (TEM), combining energy dispersive X-ray spectroscopy (EDX). The microstructures of both ceramics were compared. Amount of impurities was lower for  $\text{ZrB}_2$  consolidated by spark plasma sintering than for hot-pressed  $\text{ZrB}_2$ . In particular, oxygen impurity was not detected even at the grain-boundaries in  $\text{ZrB}_2$  consolidated by spark plasma sintering. The cleaning effect generated on the powder surfaces during spark plasma sintering cycle was displayed. In addition, dislocations were present only in the spark plasma sintered  $\text{ZrB}_2$  ceramic, as a result of localized high stresses.

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## 1. Introduction

Spark plasma sintering (SPS) is one of the most recent advanced processing techniques developed for densifying ceramic materials [1,2]. Although SPS is similar to hot-pressing (HP), in place of indirect heating, the applied electrical field heats the die and the powder compact. The SPS makes it possible to sinter body material at lower temperatures and in a shorter time than in conventional hot-press sintering. Previous studies [3–5] on several carbide, nitride, and oxide ceramics have also shown that the SPS produced almost full density at a lower temperature, with a considerable shorter sintering time (within minutes), compared to hot-pressing, thereby retaining fine and homogeneous microstructure. Recent studies have shown that SPS enhanced densification and the refined microstructure can be achieved in very short processing cycles for  $\text{ZrB}_2$ -based ceramics [6–8]. For example,  $\text{ZrB}_2$ - $\text{ZrC}$ - $\text{SiC}$  compositions could be sintered to fully dense compacts with fine and homogenous microstructure at 1950 °C and 30 MPa for 2 min [7], by using the SPS technique. Full densified pure  $\text{ZrB}_2$

could be achieved at 1900 °C and 50 MPa for 3 min [8] by SPS as well. For comparison, the  $\text{ZrB}_2$  produced by HP achieved a relative density of ~91% even at 2000 °C and 30 MPa for 60 min [9]. Hence, the SPS process could be used to enhance densification of poorly sinterable ceramics, by simultaneously applying a uniaxial load and a direct or pulsed electric current to a powder compact.

It has been recognized that the SPS enhances densification and improves sinterability of  $\text{ZrB}_2$ -based ceramics. However, the densification enhancing mechanism – mainly whether or how an electric discharge is involved in accelerating the densification and grain growth – is still the subject of intense debate. Four factors that contribute to the fast densification process can be discerned: (i) an efficient heat transfer; (ii) the use of comparatively high pressure; (iii) the presence of an electrical field (use of DC pulses); and (iv) the presence of local spark discharges generated between the powder particles under high-energy electrical pulses. Presumably, the presence of discharge cleans the powder surfaces from adsorbed species, promoting their activation [1]. The presence of cleaned and activated surfaces is expected to enhance the grain boundary diffusion, therefore densification. Obviously, it is important to identify whether the cleaning effect is present or absent during the SPS cycle. It could be expected the impurities at the grains

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boundary of the sintered  $\text{ZrB}_2$  compacts to be considerably lower for the SPS samples than for the HP ones when the cleaning effect was present on the powder surfaces. In this study, the grain-boundary microstructures of  $\text{ZrB}_2$  ceramics produced by SPS and HP were characterized by transmission electron microscopy. Also, the chemical compositional analysis of grain-boundaries for the both  $\text{ZrB}_2$  ceramics was carried out by an energy dispersive X-ray spectroscopy (EDX) under the TEM observations.

## 2. Experimental

Commercially available  $\text{ZrB}_2$  powder (Grade F, Japan New Metals Co., Ltd., Tokyo) was used in this study. The particle size of the powder is in the range of 1.5–2.5  $\mu\text{m}$ , with an average grain diameter of 2.1  $\mu\text{m}$ . The elemental impurities are (wt.%): O 1.06, C 0.27, N 0.19, and a few of Cr, Fe and Hf. In order to eliminate large  $\text{ZrB}_2$  agglomerates, the starting  $\text{ZrB}_2$  powder was homogenized by ball milling in silicon carbide media using ethanol as a solvent for 24 h and the resulting slurry was then dried. The powder was put into a graphite die lines with graphite foil and densified using plasma spark sintering (SPS-1030, Sumitomo Coal Mining Co. Ltd., Tokyo, Japan). The sintering was performed at 1900 °C and 50 MPa for 3 min in vacuum ( $\sim 6 \times 10^{-2}$  Pa), with heating rate of  $\sim 200$  °C/min. The load was removed when the die temperature dropped to below 1000 °C, with the cooling rate of  $\sim 600$  °C/min. In addition, the hot-pressed  $\text{ZrB}_2$  samples were prepared for comparison. The hot-pressing was conducted at 2000 °C for 60 min under an external pressure of 30 MPa in vacuum. The detailed SPS and HP processes were reported elsewhere [8,9]. The SPS and HP sintering conditions, relative density, and grain diameter of the resulting specimens were summarized in Table 1.

The crystalline structure of the  $\text{ZrB}_2$  ceramics consolidated by HP and SPS was identified by X-ray diffraction (XRD; RINT2500, Rigaku Co. Ltd., Tokyo, Japan) with Cu  $K\alpha$  and an accelerating voltage of 40 kV and a current of 200 mA. Thin specimens for TEM observations were mechanically ground to a thickness of  $\sim 80$   $\mu\text{m}$ , then dimpling to a thickness of  $\sim 20$   $\mu\text{m}$  in the center of the disks and additional  $\text{Ar}^+$ -ion beam thinning at accelerating voltage of 4 kV. The microstructures of both ceramics were investigated by transmission electron microscopy (JEOL JEM-2010F) operated at 200 kV. Energy dispersive X-ray spectroscopy (EDX) analysis was also done using a NORAN 663D spectrometer during TEM observation in order to determine impurities inside the grains and at the grain-boundaries for the SPS and HP sintered  $\text{ZrB}_2$  ceramics.

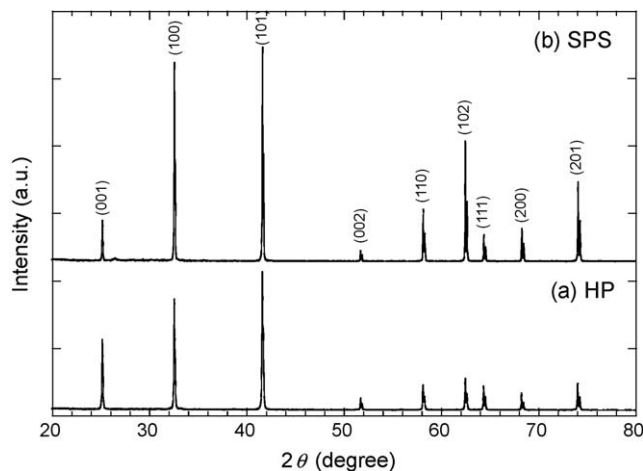


Fig. 1. X-ray diffraction patterns of the  $\text{ZrB}_2$  ceramics consolidated by (a) HP and (b) SPS.

## 3. Results and discussion

In Fig. 1, the X-ray diffraction patterns for the both  $\text{ZrB}_2$  ceramics consolidated by HP and SPS are presented. Only hexagonal  $\text{ZrB}_2$  phase was detected in both sintered materials, whereas the intergranular secondary phase was not detected for both materials. In Fig. 2, a bright-field TEM image of the hot-pressed  $\text{ZrB}_2$  is presented. Most of the grains showed equiaxed shape with average grain diameter of 4.5  $\mu\text{m}$ . However, several grains had preferentially grown to an elongated rod with an average aspect ratio of  $\sim 1.8$ . The EDX spectra of the inside of  $\text{ZrB}_2$  grain and the grain boundary (marked A and B in Fig. 2(a)) are shown in Fig. 2(b) and (c), respectively. Characteristic X-rays of B, O, Cu, Zr and Hf elements were present inside the  $\text{ZrB}_2$  grain (Fig. 2(b)). Note that the Cu signals are from background generated from Cu mesh. O and Hf result from the impurities of the starting  $\text{ZrB}_2$  powders and they are also present inside the  $\text{ZrB}_2$  grains. On the other hand, Fe and Cr are present at the grain-boundaries as well (Fig. 2(c)). Also, the amounts of the impurities are significantly higher at the grain-boundaries than inside the  $\text{ZrB}_2$  grains. Impurities presence inhibited the densification of the  $\text{ZrB}_2$  ceramic and promoted grain growth during the hot-pressing sintering.

In Fig. 3, a bright-field TEM image of the  $\text{ZrB}_2$  ceramic consolidated by SPS is presented. The  $\text{ZrB}_2$  ceramic consolidated by SPS showed fine and homogenous microstructure which consisted of almost equiaxed grains, compared to the hot-pressed  $\text{ZrB}_2$  ceramic (Fig. 2(a)). The average grain size was approximately 2.7  $\mu\text{m}$ , i.e. smaller than for hot-pressed  $\text{ZrB}_2$  (Table 1). This is attributed to a lower sintering

Table 1  
Sintering conditions, densities, and average grain size of the  $\text{ZrB}_2$  ceramics consolidated by HP and SPS.

Sintering route	Consolidated conditions	Theoretical density ( $\text{g}/\text{cm}^3$ )	Measured density ( $\text{g}/\text{cm}^3$ )	Relative density (%TD)	Average grain size of $\text{ZrB}_2$	
					d ( $\mu\text{m}$ )	Aspect ratio
Hot-pressing	2000 °C/60 min/30 MPa/vacuum	6.09	5.51	90.4	4.5	1.8
Spark plasma sintering	1900 °C/3 min/50 MPa/vacuum	6.09	5.94	97.6	2.7	1.2

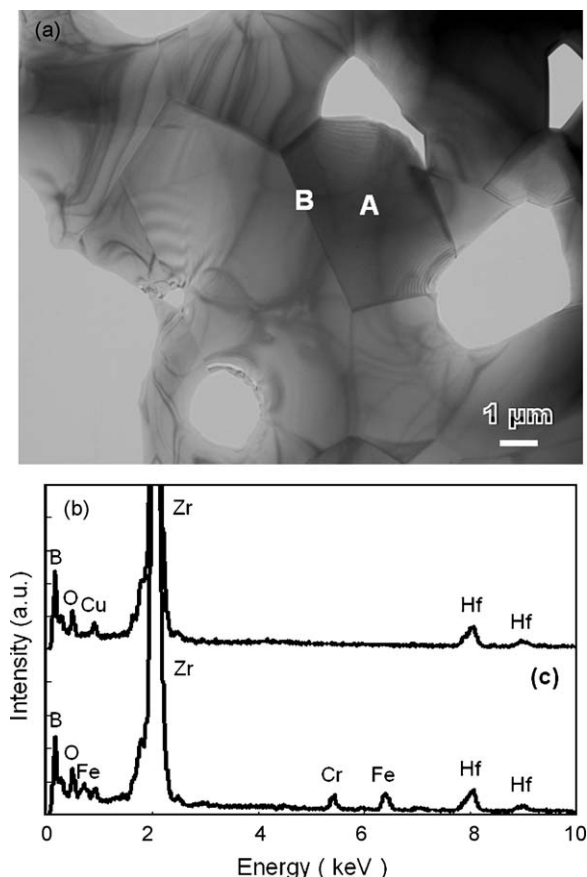


Fig. 2. (a) TEM bright-field image, and EDX spectra obtained (b) inside the  $\text{ZrB}_2$  grain (marked A in (a)), and (c) at the grain-boundary (marked B in (a)) for the  $\text{ZrB}_2$  ceramics consolidated by HP.

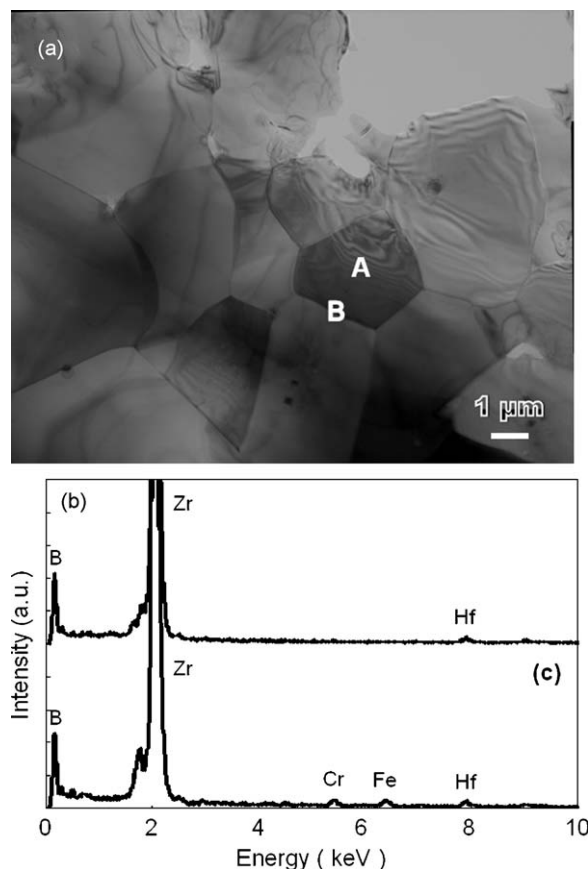


Fig. 3. (a) TEM bright-field image, and EDX spectra obtained (b) inside the  $\text{ZrB}_2$  grain (marked A in (a)), and (c) at the grain-boundary (marked B in (a)) for the  $\text{ZrB}_2$  ceramics consolidated by SPS.

temperature and much shorter sintering time for SPS than for HP (Table 1). The EDX spectra of the inside of  $\text{ZrB}_2$  grain and the grain boundary (marked A and B in Fig. 3(a)) are shown in Fig. 3(b) and (c), respectively. Only Hf impurity is present inside the  $\text{ZrB}_2$  grains, whereas Cr, Hf and Fe are detected at the grain-boundaries. Furthermore, the intensities of the Hf peak detected inside the grains are almost the same as at the grain-boundaries. In addition, the intensities of these impurities are considerably lower for the SPS specimens than for the HP ones (Fig. 2(b) and (c)). In particular, oxygen was not detected either inside the  $\text{ZrB}_2$  grains or at the grain-boundaries for the SPS specimen. Obviously, the absence of oxygen and the reduced amount of Hf, Cr and Fe impurities are closely linked to the high-energy electrical pulse during the SPS cycle; indeed, oxygen was present inside the grains and at the grain-boundaries for the hot-pressed  $\text{ZrB}_2$  ceramic (Fig. 2(b) and (c)), demonstrating that cleaning of  $\text{ZrB}_2$  particles surfaces results from the SPS cycle. Presumably, the presence of oxygen within the  $\text{ZrB}_2$  grains for the hot-pressed  $\text{ZrB}_2$  ceramic is probably a result of inward diffusion of oxygen impurities ( $\text{B}_2\text{O}_3$  and  $\text{ZrO}_2$ ) present on the  $\text{ZrB}_2$  powder surfaces during hot-pressing sintering. It should be believable that this cleaning effect results from the spark discharge generated between the powder particles under a high-energy electrical pulse during the SPS cycle.

Oxygen impurities ( $\text{B}_2\text{O}_3$  and  $\text{ZrO}_2$ ) present on the starting powder surfaces have been shown to inhibit densification and to promote grain growth in non-oxide ceramic systems [10,11]. A study [11] on  $\text{TiB}_2$  suggested that the total oxygen content must be less than 0.5 wt.% to achieve full density. Thus, it is important to reduce the amount of oxygen for enhancing densification and improving sinterability. Previous studies [12–14] on  $\text{ZrB}_2$  ceramics with nitride additives, e.g.  $\text{Si}_3\text{N}_4$ ,  $\text{AlN}$ ,  $\text{HfN}$  or  $\text{ZrN}$ , showed their suitability is effective additives for improving sinterability or/and enhancing densification of  $\text{ZrB}_2$ . The main reason for incorporating nitrides as additives is the propensity of nitrides to consume the oxygen-bearing species on the diboride powder surfaces. The reduction of oxygen results in higher boron activity, which is one of the conditions favouring lattice diffusion and, therefore, densification [11]. Thus, the fine and homogenous microstructure as well as the lower sintering temperature required for SPS specimens is attributed to oxygen absence as well as other impurities reduction on the  $\text{ZrB}_2$  powder surfaces during the SPS cycle. This cleaning effect occurring at the initial stage of sintering results in cleaned and active surfaces of  $\text{ZrB}_2$  particles, a factor that is expected to enhance the grain boundary diffusion, and thus densification.

Moreover, some dislocations were observed in the  $\text{ZrB}_2$  ceramics consolidated by SPS (Fig. 4). These dislocations

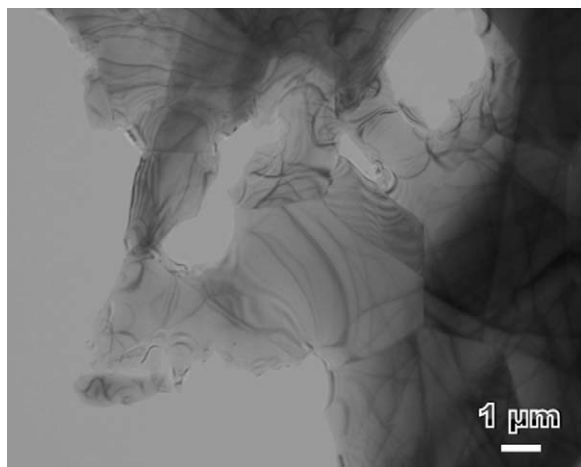


Fig. 4. TEM bright-field image of the  $\text{ZrB}_2$  ceramics consolidated by SPS, showing dislocations presence in the  $\text{ZrB}_2$  grains.

originated from the  $\text{ZrB}_2$  grains boundaries and cross the grains, suggesting the  $\text{ZrB}_2$  grains to be deformed during the SPS cycle. However, dislocations were not observed in the hot-pressed  $\text{ZrB}_2$  ceramics (Fig. 2(a)). A study [15] in  $\text{ZrB}_2$ – $\text{ZrC}$  composite consolidated by SPS at 1800 °C and 50 MPa for 5 min showed well-ordered dislocations in the  $\text{ZrB}_2$  grains, whose presence was attributed to a localized high stresses originated from the sharp thermal gradient during the SPS cycle. Similar effect may be effective in fast cooling cycle (cooling rate:  $\sim 600$  °C/min) utilized in this study.

#### 4. Conclusions

The microstructure of hot-pressed  $\text{ZrB}_2$  ceramics consisted of equiaxed grains and a few of elongated grains. The microstructure of spark plasma sintered  $\text{ZrB}_2$  ceramic consisted of equiaxed grains. The average diameter of grains was smaller for the spark plasma sintered  $\text{ZrB}_2$  ceramics than for the hot-pressed ones. This was attributed to the lower sintering temperature and very shorter sintering time for SPS, compared to HP. O and Hf were present inside the  $\text{ZrB}_2$  grains and at the grain-boundaries of hot-pressed  $\text{ZrB}_2$ , whereas Cr and Fe were found only at the grain-boundaries. For the spark plasma sintered  $\text{ZrB}_2$ , on the other hand, oxygen was not detected neither inside  $\text{ZrB}_2$  grains nor at the grain-boundaries. A few Cr, Fe and Hf were present at the grain-boundaries. Oxygen

absence and the low impurity content at the grain-boundaries were attributed to the cleaning of  $\text{ZrB}_2$  particles surfaces during the SPS cycle, resulting from the spark discharge generated between  $\text{ZrB}_2$  powder particles under high-energy electrical pulses. In addition, dislocations were present only in the  $\text{ZrB}_2$  ceramics consolidated by SPS, whose presence was associated to localized high stresses which originated from the sharp thermal gradient during cooling.

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